

# 74HC1G126; 74HCT1G126

Bus buffer/line driver; 3-state

Rev. 04 — 20 July 2007

Product data sheet

## 1. General description

The 74HC1G126 and 74HCT1G126 are high-speed, Si-gate CMOS devices. They provide one non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input pin (OE). A LOW at pin OE causes the output to assume a high-impedance OFF-state.

The HC device has CMOS input switching levels and supply voltage range 2 V to 6 V.

The HCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

The bus driver output currents are equal to those of the 74HC126 and 74HCT126.

## 2. Features

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options

## 3. Ordering information

Table 1. Ordering information

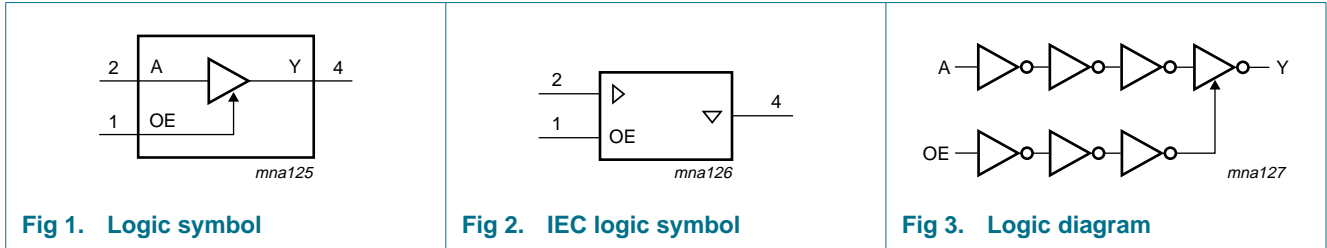
Type number	Package			
	Temperature range	Name	Description	Version
74HC1G126GW 74HCT1G126GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74HC1G126GV 74HCT1G126GV	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753

## 4. Marking

Table 2. Marking codes

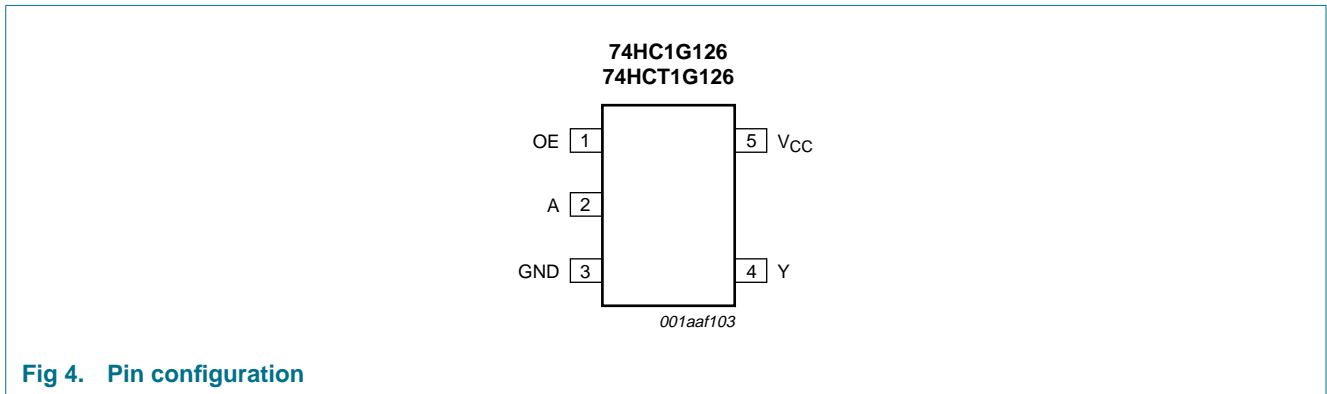
Type number	Marking
74HC1G126GW	HN
74HCT1G126GW	TN
74HC1G126GV	H26
74HCT1G126GV	T26

## 5. Functional diagram



## 6. Pinning information

### 6.1 Pinning



### 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
OE	1	output enable input
A	2	data input
GND	3	ground (0 V)
Y	4	data output
V <sub>CC</sub>	5	supply voltage

## 7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state

Inputs		Output
OE	A	Y
H	L	L
H	H	H
L	X	Z

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [\[1\]](#)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V	-	±20	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V	-	±20	mA
I <sub>O</sub>	output current	-0.5 V < V <sub>O</sub> < V <sub>CC</sub> + 0.5 V	-	±35.0	mA
I <sub>CC</sub>	supply current		-	70	mA
I <sub>GND</sub>	ground current		-70	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	<a href="#">[2]</a> -	200	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] Above 55 °C the value of P<sub>tot</sub> derates linearly with 2.5 mW/K.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74HC1G126			74HCT1G126			Unit
			Min	Typ	Max	Min	Typ	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V <sub>I</sub>	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
V <sub>O</sub>	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	-	139	-	-	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

## 10. Static characteristics

**Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T<sub>amb</sub> = 25 °C.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
<b>For type 74HC1G126</b>								
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	V

**Table 7. Static characteristics ...continued**

Voltages are referenced to GND (ground = 0 V). All typical values are measured at  $T_{amb} = 25\text{ }^\circ\text{C}$ .

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.84	4.32	-	3.7	-	V
		I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.34	5.81	-	5.2	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.33	-	0.4	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	1.0	-	1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	5	-	10	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	10	-	20	μA
C <sub>I</sub>	input capacitance		-	1.5	-	-	-	pF
<b>For type 74HCT1G126</b>								
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V						
		I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	V
		I <sub>O</sub> = -6.0 mA	3.84	4.32	-	3.7	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V						
		I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	V
		I <sub>O</sub> = 6.0 mA	-	0.16	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	1.0	-	1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	5	-	10	
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	10	-	20	μA
ΔI <sub>CC</sub>	additional supply current	per input; V <sub>CC</sub> = 4.5 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; I <sub>O</sub> = 0 A	-	-	500	-	850	μA
C <sub>I</sub>	input capacitance		-	1.5	-	-	-	pF

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**

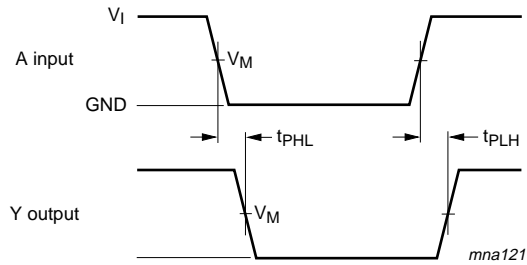
$GND = 0\text{ V}$ ;  $t_r = t_f \leq 6.0\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless otherwise specified. All typical values are measured at  $T_{amb} = 25\text{ }^\circ\text{C}$ . For test circuit see [Figure 7](#)

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit	
			Min	Typ	Max	Min	Max		
<b>For type 74HC1G126</b>									
$t_{pd}$	propagation delay	A to Y; see <a href="#">Figure 5</a>	<a href="#">[1]</a>						
		$V_{CC} = 2.0\text{ V}$	-	24	125	-	150	ns	
		$V_{CC} = 4.5\text{ V}$	-	10	25	-	30	ns	
		$V_{CC} = 5.0\text{ V}$ ; $C_L = 15\text{ pF}$	-	9	-	-	-	ns	
		$V_{CC} = 6.0\text{ V}$	-	9	21	-	26	ns	
$t_{en}$	enable time	OE to Y; see <a href="#">Figure 6</a>	<a href="#">[1]</a>						
		$V_{CC} = 2.0\text{ V}$	-	24	155	-	190	ns	
		$V_{CC} = 4.5\text{ V}$	-	10	31	-	38	ns	
		$V_{CC} = 6.0\text{ V}$	-	8	26	-	32	ns	
$t_{dis}$	disable time	OE to Y; see <a href="#">Figure 6</a>	<a href="#">[1]</a>						
		$V_{CC} = 2.0\text{ V}$	-	16	155	-	190	ns	
		$V_{CC} = 4.5\text{ V}$	-	12	31	-	38	ns	
		$V_{CC} = 6.0\text{ V}$	-	11	26	-	32	ns	
$C_{PD}$	power dissipation capacitance	$V_I = GND\text{ to }V_{CC}$	<a href="#">[2]</a>	-	30	-	-	-	pF
<b>For type 74HCT1G126</b>									
$t_{pd}$	propagation delay	A to Y; see <a href="#">Figure 5</a>	<a href="#">[1]</a>						
		$V_{CC} = 4.5\text{ V}$	-	11	30	-	36	ns	
		$V_{CC} = 5.0\text{ V}$ ; $C_L = 15\text{ pF}$	-	10	-	-	-	ns	
$t_{en}$	enable time	OE to Y; see <a href="#">Figure 6</a> ; $V_{CC} = 4.5\text{ V}$	<a href="#">[1]</a>	-	10	35	-	42	ns
$t_{dis}$	disable time	OE to Y; see <a href="#">Figure 6</a> ; $V_{CC} = 4.5\text{ V}$	<a href="#">[1]</a>	-	12	31	-	38	ns
$C_{PD}$	power dissipation capacitance	$V_I = GND\text{ to }V_{CC} - 1.5\text{ V}$	<a href="#">[2]</a>	-	27	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  
 $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .  
 $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

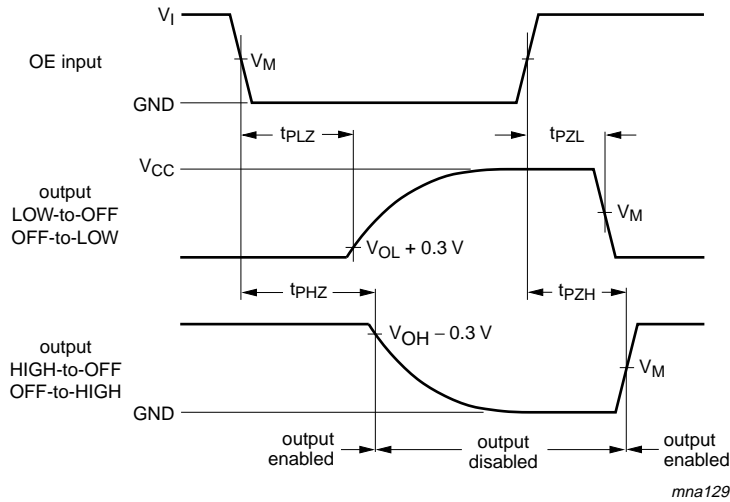
- [2]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu\text{W}$ ).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:  
 $f_i$  = input frequency in MHz  
 $f_o$  = output frequency in MHz  
 $C_L$  = output load capacitance in pF  
 $V_{CC}$  = supply voltage in Volts  
 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs

12. Waveforms



Measurement points are given in [Table 9](#).

Fig 5. The input (A) to output (Y) propagation delays

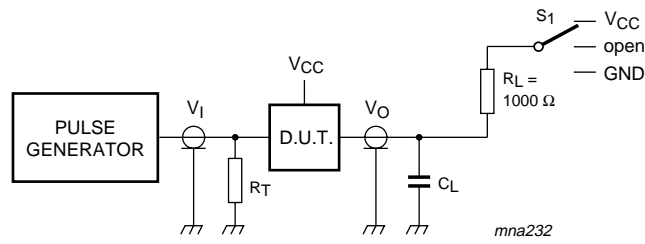


Measurement points are given in [Table 9](#).

Fig 6. The 3-state enable and disable times

Table 9. Measurement points

Type	Input		Output
	$V_M$	$V_I$	$V_M$
74HC1G126	$0.5 \times V_{CC}$	GND to $V_{CC}$	$0.5 \times V_{CC}$
74HCT1G126	1.3 V	GND to 3.0 V	1.3 V



Test data is given in [Table 8](#). Definitions for test circuit:

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator

$C_L$  = Load capacitance including jig and probe capacitance

$R_L$  = Load resistance

For  $t_{PLH}$ ,  $t_{PHL}$ ,  $S_1$  = open

For  $t_{PLZ}$ ,  $t_{PZL}$ ,  $S_1$  =  $V_{CC}$

For  $t_{PHZ}$ ,  $t_{PZH}$ ,  $S_1$  = GND

**Fig 7. Load circuitry for switching times**

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

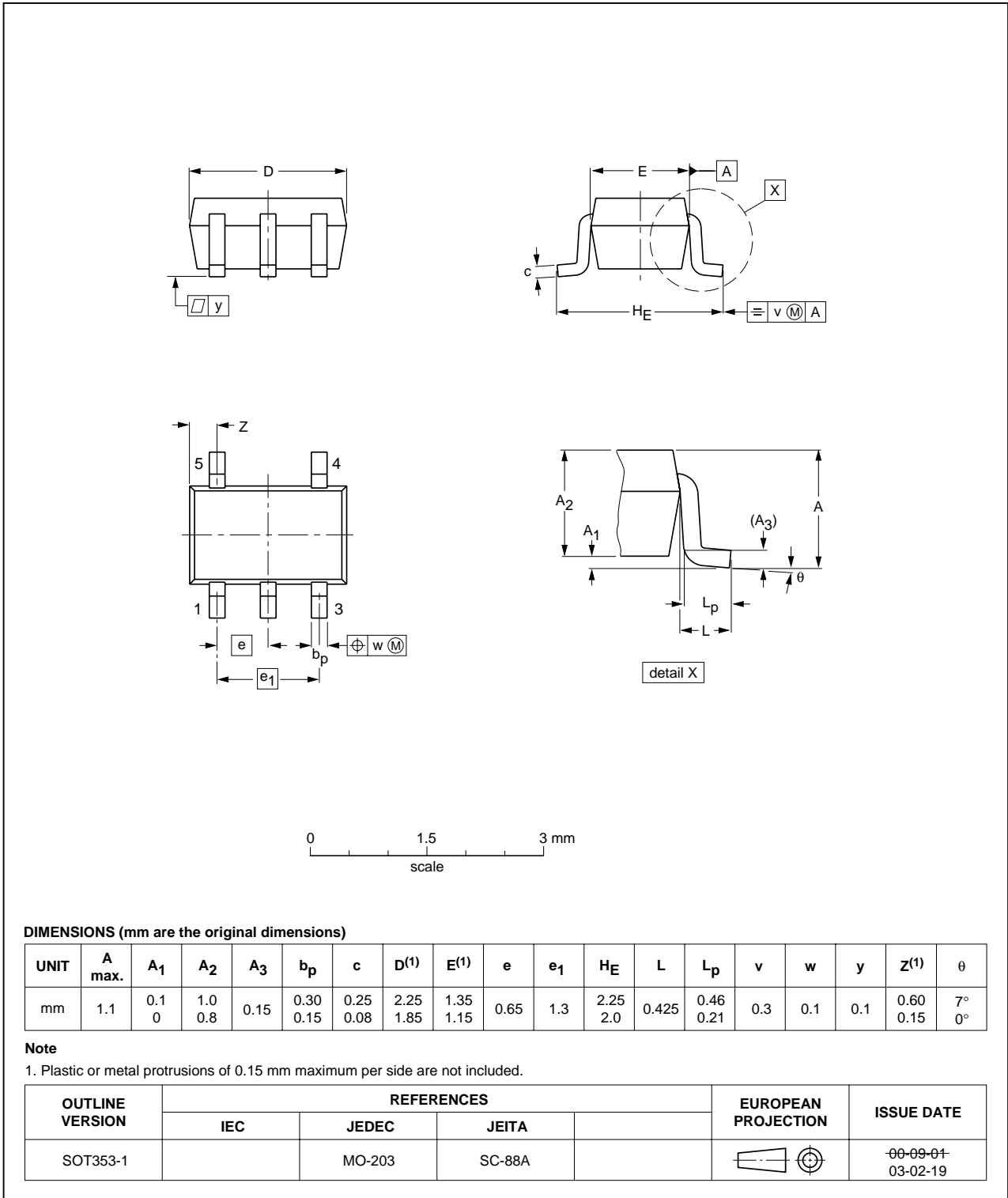


Fig 8. Package outline SOT353-1 (TSSOP5)



Plastic surface-mounted package; 5 leads

SOT753

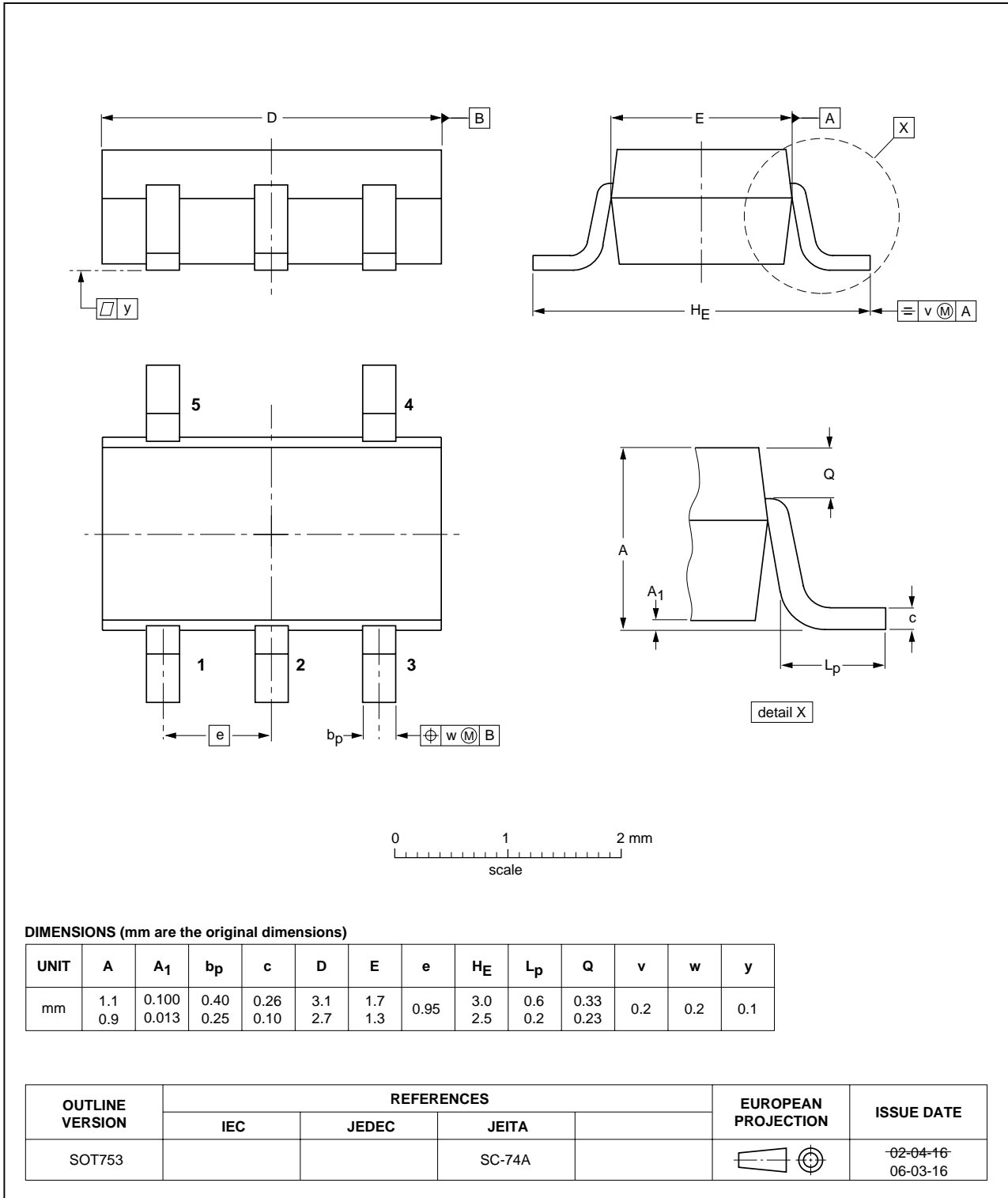


Fig 9. Package outline SOT753 (SC-74A)

## 14. Abbreviations

Table 10. Abbreviations

Acronym	Description
DUT	Device Under Test
TTL	Transistor-Transistor Logic

## 15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT1G126_4	20070720	Product data sheet	-	74HC_HCT1G126_3
Modifications:	<ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Package SOT353 changed to SOT353-1 in <a href="#">Table 1</a> and <a href="#">Figure 8</a>.</li> <li>Quick Reference Data and Soldering sections removed.</li> <li><a href="#">Section 2 "Features"</a> updated.</li> </ul>			
74HC_HCT1G126_3	20020515	Product specification	-	74HC_HCT1G126_2
74HC_HCT1G126_2	20010406	Product specification	-	74HC_HCT1G126
74HC_HCT1G126	19970924	Preliminary specification	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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